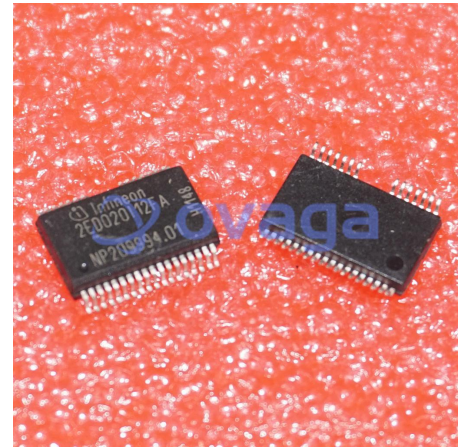


Mosfet & power driver ics dual channel igbt driver ic +/-1200v

Manufacturers	Infineon Technologies Corporation
Package/Case	DSO-36
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for 2ED020I12FA or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

2ED020I12FA is a specific model number for a power module, which is a type of electronic device that combines multiple components, such as transistors, diodes, and capacitors, into a single package.

Features

2ED020I12FA is a half-bridge power module with a built-in gate driver

It has a maximum operating temperature of 175°C

It can handle a maximum current of 20A and a maximum voltage of 1200V

It has short-circuit protection and under-voltage lockout protection

Application

2ED020I12FA is commonly used in power electronics applications such as motor control, solar inverters, and power supplies

It can also be used in automotive applications, such as electric and hybrid vehicles.

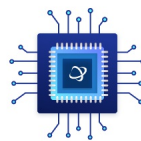


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